Unit: mm

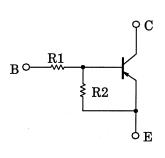
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) (Bias Resistor built-in Transistor)

RN2421, RN2422, RN2423, RN2424 RN2425, RN2426, RN2427

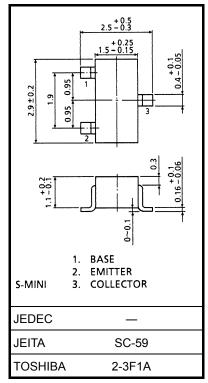
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- High current type $(I_{C(MAX)} = -800 \text{ mA})$
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Low VCE (sat)
- Complementary to RN1421 to RN1427

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)		
RN2421	1	1		
RN2422	2.2	2.2		
RN2423	4.7	4.7		
RN2424	10	10		
RN2425	0.47	10		
RN2426	1	10		
RN2427	2.2	10		



Weight: 0.012 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	CS	Symbol	Rating	Unit	
Collector-Base voltage	RN2421 to 2427	V _{CBO}	-50	V	
Collector-Emitter voltage	11112421102421	V _{CEO}	-50	V	
	RN2421 to 2424		-10	V	
Emitter-Base voltage	RN2425, 2426	V _{EBO}	-5		
	RN2427		-6		
Collector current		Ι _c	-800	mA	
Collector power dissipation	RN2421 to 2427	Pc	200	mW	
Junction temperature	RN2421 (0 2427	Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 1988-02

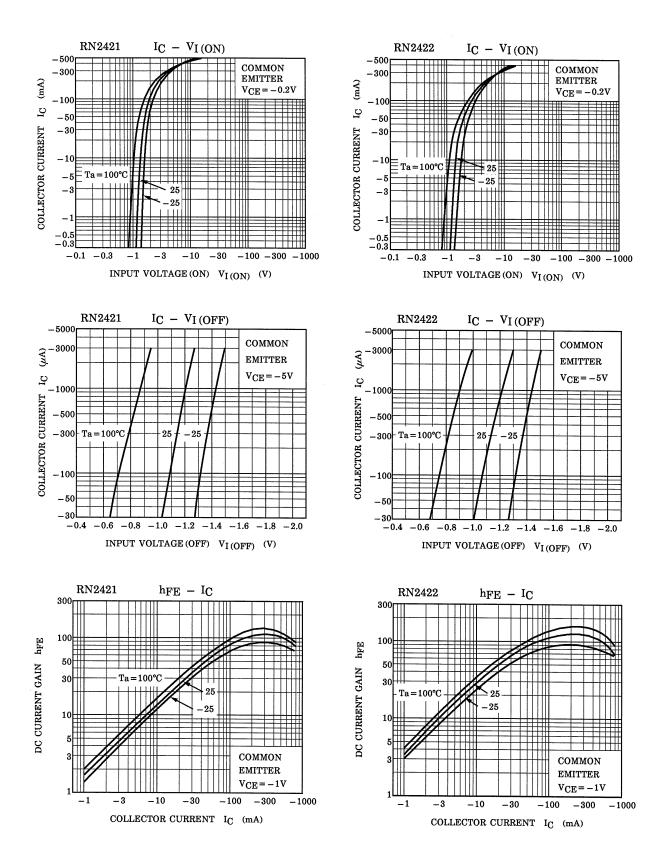
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2421 to 2427	000	_	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
	RIN2421 10 2427		_	V _{CE} = -50V, I _B = 0	_		-500	
	RN2421	IEBO	_	V _{EB} = -10V, I _C = 0	-3.85	_	-7.14	
	RN2422		_		-1.75	_	-3.25	
	RN2423				-0.82	—	-1.52	
Emitter cut-off current	RN2424		_		-0.38	_	-0.71	mA
	RN2425			$V_{EB} = -5V, I_C = 0$ $V_{EB} = -6V, I_C = 0$	-0.365	—	-0.682	
	RN2426		_		-0.35	_	-0.65	
	RN2427		_		-0.378	_	-0.703	
	RN2421		_		60	_	_	
	RN2422		_		65	_	_	
	RN2423				70			
DC current gain	RN2424	h _{FE}	_	V _{CE} = −1V, I _C = −100mA	90		_	
	RN2425		_		90		_	
	RN2426				90	_	_	
	RN2427			4	90	_	_	
Collector-Emitter	RN2421			I _C = −50mA, I _B = −2mA				
saturation voltage	RN2422 to 2427	V _{CE (sat)}	—	$I_{\rm C} = -50 {\rm mA}, I_{\rm B} = -1 {\rm mA}$	-	_	-0.25	V
	RN2421	VI (ON)	_	V _{CE} = -0.2V I _C = -100mA	-1.0	_	-3.5	V
	RN2422		—		-1.4	_	-4.5	
	RN2423		_		-2.0	_	-6.5	
Input voltage (ON)	RN2424		_		-3.0	_	-12.0	
	RN2425		_		-0.6	_	-2.0	
	RN2426		_		-0.7	_	-2.5	
	RN2427		_		-1.0		-3.0	
	RN2421 to 2424	V _{I (OFF)}	_	V _{CE} = -5V, I _C = -0.1mA	-0.8	—	-1.3	v
Input voltage (OFF)	RN2425, 2426		_		-0.4		-0.8	
	RN2427		_		-0.5	_	-1.0	
Transition frequency	RN2421 to 2427	f _T	—	$V_{CE} = -5V, I_C = -20mA$	—	200	_	MHz
Collector output capacitance	RN2421 to 2427	C _{ob}	—	V _{CB} = -10V, I _E = 0 f = 1MHz	-	13	—	pF
	RN2421				0.7	1.0	1.3	kΩ
	RN2422	R1			1.54	2.2	2.86	
	RN2423				3.29	4.7	6.11	
Input resistor	RN2424		_		7	10	13	
	RN2425		_		0.329	0.47	0.61	
	RN2426		_		0.7	1.0	1.3	
	RN2427		_		1.54	2.2	2.86	
	RN2421 to 2424	- R1/R2	_		0.9	1.0	1.1	
	RN2425				0.0423	0.047	0.0517	
Resistor ratio	RN2426		_		0.09	0.1	0.11	
	RN2427		_		0.2	0.22	0.24	

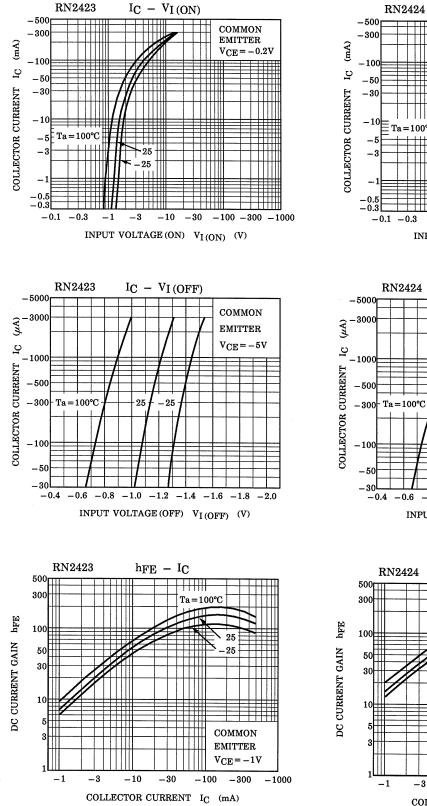
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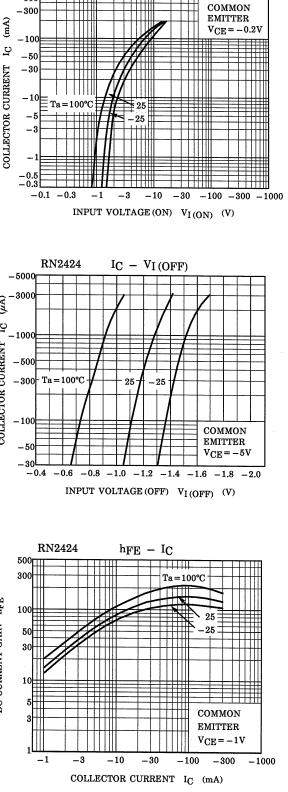
Marking

Type No.	Marking
RN2421	R A Type name
RN2422	
RN2423	
RN2424	R D H
RN2425	R E
RN2426	
RN2427	

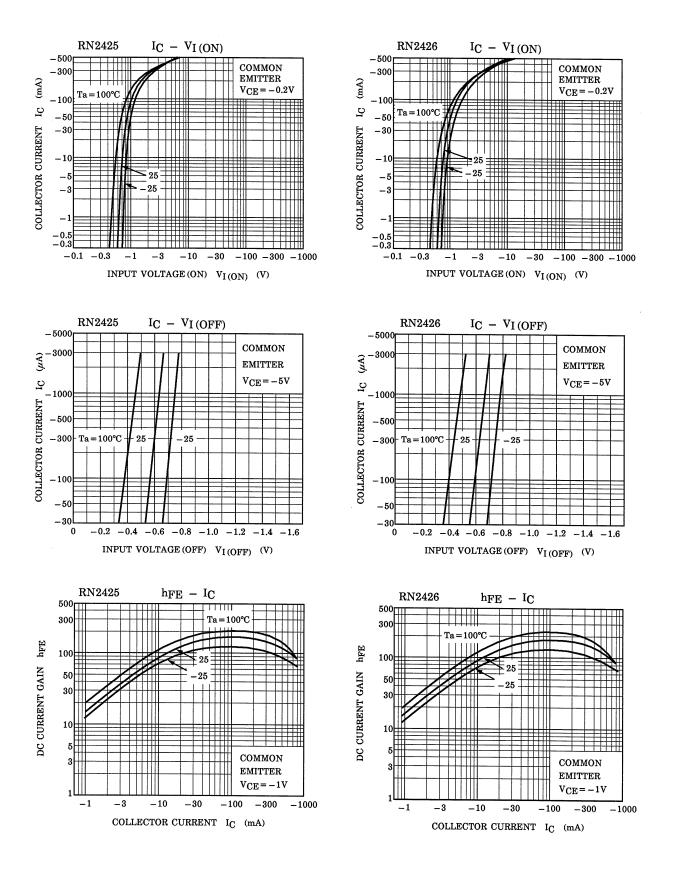


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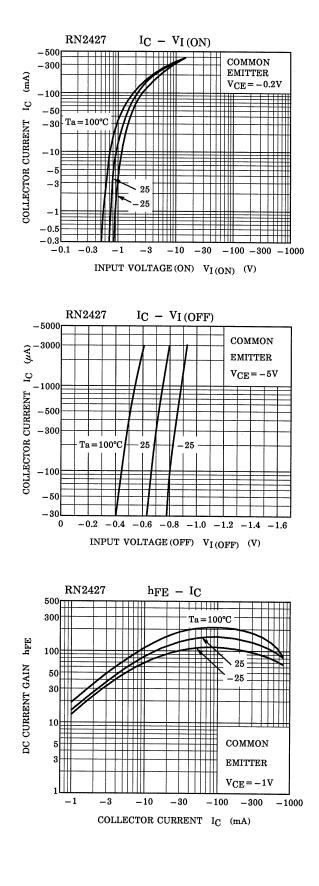




 $I_C - V_I(ON)$



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